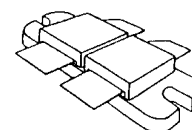


SD1485

RF & MICROWAVE TRANSISTORS TV/LINEAR APPLICATIONS

Features

- 170 - 230 MHz
- 32 VOLTS
- $P_{OUT} = 200$ WATTS
- $G_P = 11.0$ dB GAIN MINIMUM
- INTERNAL INPUT MATCHING
- COMMON EMITTER CONFIGURATION

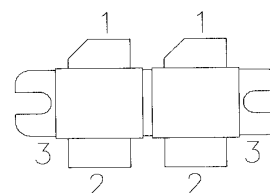


2 x .437 x .450 2LFL (M175)
 epoxy sealed

DESCRIPTION:

The SD1485 is a gold metallized epitaxial silicon NPN planar transistor using diffused emitter ballast resistors for high linearity Class AB operation in VHF and Band III television transmitters and transposers.

PIN CONNECTION



1. Collector 3. Emitter
 2. Base

ABSOLUTE MAXIMUM RATINGS (T_{case} = 25°C)

Symbol	Parameter	Value	Unit
V_{CBO}	Collector-Base Voltage	65	V
V_{CEO}	Collector-Emitter Voltage	35	V
V_{EBO}	Emitter-Base Voltage	3.0	V
I_C	Device Current	25	A
P_{DISS}	Power Dissipation	385	W
T_J	Junction Temperature	200	°C
T_{STG}	Storage Temperature	-65 to +150	°C

Thermal Data

$R_{TH(J-C)}$	Thermal Resistance Junction-case	0.45	°C/W
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ELECTRICAL SPECIFICATIONS (Tcase = 25°C)

STATIC

Symbol	Test Conditions		Value			Unit
			Min.	Typ.	Max.	
BV_{CBO}	I _C = 100 mA	I _E = 0 mA	65	---	---	V
BV_{CER}	I _C = 100 mA	R _{BE} = 15 Ω	60	---	---	V
BV_{CEO}	I _C = 100 mA	I _B = 0 mA	35	---	---	V
BV_{EBO}	I _E = 20 mA	I _C = 0 mA	3.0	---	---	V
I_{CES}	V _{CE} = 32 V	I _E = 0 mA	---	---	10	mA
HFE	V _{CE} = 5 V	I _C = 4 A	20	---	70	---

DYNAMIC

Symbol	Test Conditions			Value			Unit
				Min.	Typ.	Max.	
P_{OUT}	f = 230 MHz	V _{CE} = 32 V	I _{CQ} = 2 x 500 mA	200	---	---	W
G_P	f = 230 MHz	V _{CE} = 32 V	I _{CQ} = 2 x 500 mA	11	---	---	dB
η_C	f = 230 MHz	V _{CE} = 32 V	I _{CQ} = 2 x 500 mA	50	---	---	%
C_{OB}	f = 1 MHz	V _{CB} = 28 V		---	---	190	pF

IMPEDANCE DATA

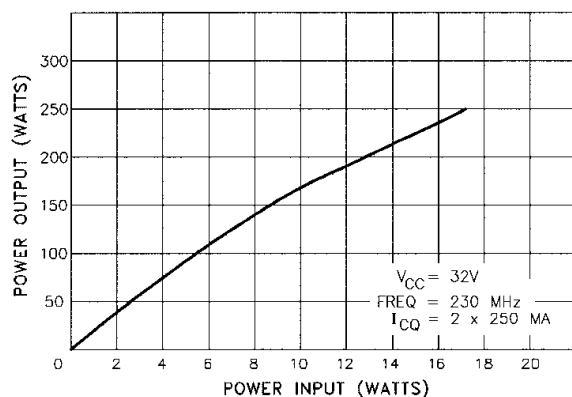
FREQ	Z _{IN} (Ω)	Z _{CL} (Ω)
170 MHz	2.7 + j1.0	3.7 + j3.0
200 MHz	2.1 + j1.5	3.4 + j3.7
230 MHz	1.4 + j2.2	3.0 + j4.1

P_{OUT} = 200W

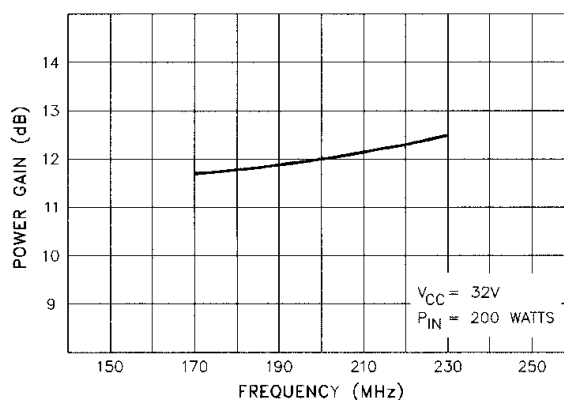
V_{CC} = 32V

TYPICAL PERFORMANCE

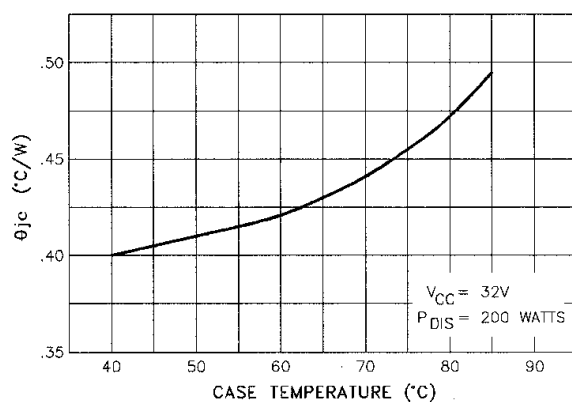
POWER OUTPUT vs POWER INPUT



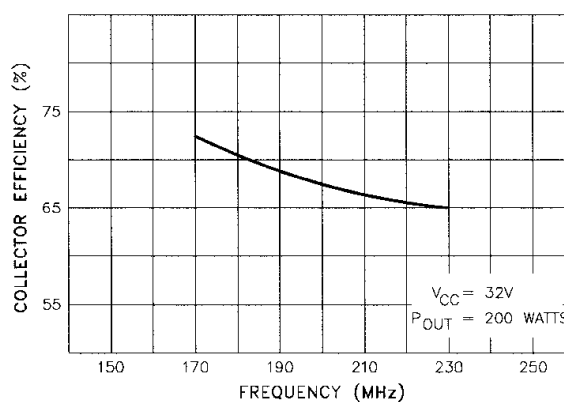
BRAODBAND POWER GAIN vs FREQUENCY



THERMAL RESISTANCE vs CASE TEMPERATURE

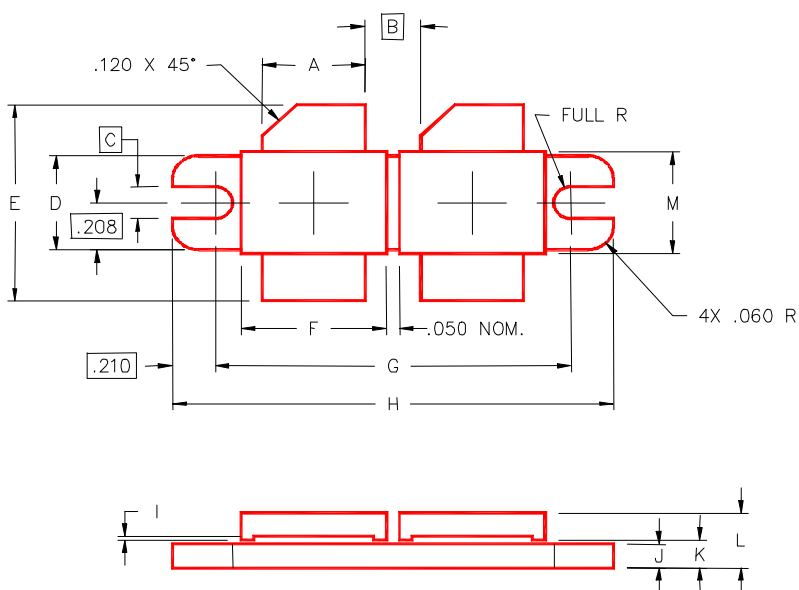


COLLECTOR EFFICIENCY vs FREQUENCY



PACKAGE MECHANICAL DATA

PACKAGE STYLE M175



	MINIMUM INCHES/MM	MAXIMUM INCHES/MM		MINIMUM INCHES/MM	MAXIMUM INCHES/MM
A	.373/9,47	.385/9,78	I	.002/0,05	.006/0,15
B	.190/4,83		J	.095/2,41	.105/2,67
C	.125/3,18		K	.115/2,92	.135/3,43
D	.411/10,44	.421/10,69	L		.250/6,35
E	.825/20,96	.865/21,97	M	.445/11,30	.455/11,56
F	.525/13,34	.535/13,59			
G	1.255/31,88	1.265/32,13			
H	1.675/42,55	1.685/42,80			